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11/06/01

PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10008389	FILING DATE 11/06/2001	CLASS 438	SUBCLASS 12	GAU 2812	EXAMINER
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**CONTINUING DATA VERIFIED: 16
17

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** FOREIGN APPLICATIONS VERIFIED:
JAPAN 2000-338708 11/07/2000

PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>	ATTORNEY DOCKET NO YKI-0079
Foreign priority claimed <input type="checkbox"/> yes <input type="checkbox"/> no		35 USC 119 conditions met <input type="checkbox"/> yes <input type="checkbox"/> no	
Verified and Acknowledged Examiners's initials			
TITLE : Bottom gate-type thin-film transistor and method for manufacturing the same			

U.S. DEPT. OF COMM/PAT & TM-PTO-438L (Rev. 10-94)

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
		Total Claims	Print Claim for O.G.
ISSUE FEE		DRAWING	
Amount Due	Date Paid	Sheets Drwg.	Figs. Drwg. Print Fig.
<input type="checkbox"/> TERMINAL DISCLAIMER		Primary Examiner PREPARED FOR ISSUE Application Examiner	
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